THS3092



HIGH-VOLTAGE, LOW-DISTORTION, CURRENT-FEEDBACK OPERATIONAL AMPLIFIERS

FEATURES

- Low Distortion
 - 66 dBc HD2 at 10 MHz, R_L = 100 Ω
 - 76 dBc HD3 at 10 MHz, R_L = 100 Ω
- Low Noise
 - 13 pA/√Hz Noninverting Current Noise
 - 13 pA/√Hz Inverting Current Noise
 - 2 nV/√Hz Voltage Noise
- High Slew Rate: 5700 V/ μ s (G = 5, V_O = 20 V_{PP})
- Wide Bandwidth: 160 MHz (G = 5, R_L = 100 Ω)
- High Output Current Drive: ±250 mA
- Wide Supply Range: ±5 V to ±15 V
- Power-Down Feature: (THS3096 Only)

APPLICATIONS

- High-Voltage Arbitrary Waveform
- Power FET Driver
- Pin Driver
- VDSL Line Driver

DESCRIPTION

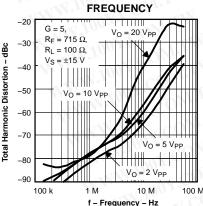
The THS3092 and THS3096 are dual high-voltage, low-distortion, high speed, current-feedback amplifiers designed to operate over a wide supply range of ±5 V to ±15 V for applications requiring large, linear output signals such as Pin, Power FET, and VDSL line drivers.

The THS3096 features a power-down pin (\overline{PD}) that puts the amplifier in low power standby mode, and lowers the quiescent current from 9.5 mA to 500 μ A.

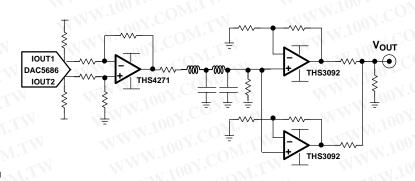
The wide supply range combined with total harmonic distortion as low as -66 dBc at 10 MHz, in addition, to the high slew rate of 5700 V/µs makes the THS3092/6 ideally suited for high-voltage arbitrary waveform driver applications. Moreover, having the ability to handle large voltage swings driving into high-resistance and high-capacitance loads while maintaining good settling time performance makes the THS3092/6 ideal for Pin driver and PowerFET driver applications.

The THS3092 is offered in an 8-pin SOIC (D), and the 8-pin SOIC (DDA) packages with PowerPAD™. The THS3096 is offered in the 8-pin SOIC (D) and the 14-pin TSSOP (PWP) packages with PowerPAD.

TOTAL HARMONIC DISTORTION vs



TYPICAL ARBITARY WAVEFORM GENERATOR OUTPUT DRIVE CIRCUIT



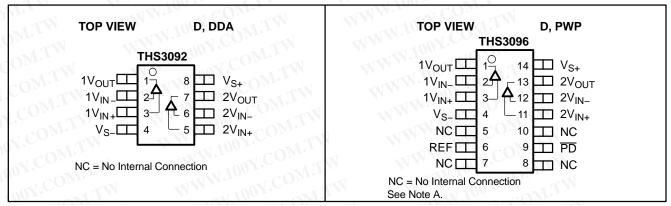
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PowerPAD is a trademark of Texas Instruments.





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.



Note A: The devices with the power down option defaults to the ON state if no signal is applied to the \overline{PD} pin. Additionallly, the REF pin functional range is from V_{S-} to $(V_{S+}-4\ V)$.

ORDERING INFORMATION

PACKAGE TYPE	TRANSPORT MEDIA, QUANTITY
0010.0	Rails, 75
SOIC-8	Tape and Reel, 2500
COIC a DD(1)	Rails, 75
SUIC-8-PP(1)	Tape and Reel, 2500
M. Inn COM.	TINN. IOU CO
2010 0	Rails, 75
30IC-8	Tape and Reel, 2500
TCCOD 44 DD(1)	Rails, 90
1330P-14-PP(1)	Tape and Reel, 2000
	PACKAGE TYPE SOIC-8 SOIC-8-PP(1) SOIC-8 TSSOP-14-PP(1)

⁽¹⁾ The PowerPAD is electrically isolated from all other pins.

DISSIPATION RATING TABLE

DACKAGE	0 (0000	O (9CAAN(1)	POWER	ER RATING ⁽²⁾	
PACKAGE	Θ _{JC} (°C/W)	Θ _{JA} (°C/W) ⁽¹⁾	T _A ≤ 25°C	T _A = 85°C	
D-8	38.3	97.5	1.02 W	410 mW	
DDA-8 ⁽³⁾	9.2	45.8	2.18 W	873 mW	
PWP-14 ⁽³⁾	2.07	37.5	2.67 W	1.07 W	

⁽¹⁾ This data was taken using the JEDEC standard High-K test PCB.

⁽²⁾ Power rating is determined with a junction temperature of 125°C. This is the point where distortion starts to substantially increase. Thermal management of the final PCB should strive to keep the junction temperature at or below 125°C for best performance and long term reliability.

⁽³⁾ The THS3092 and THS3096 may incorporate a PowerPAD™ on the underside of the chip. This acts as a heatsink and must be connected to a thermally dissipating plane for proper power dissipation. Failure to do so may result in exceeding the maximum junction temperature which could permanently damage the device. See TI Technical Brief SLMA002 for more information about utilizing the PowerPAD™ thermally enhanced package.



RECOMMENDED OPERATING CONDITIONS

		MIN	MAX	UNIT
Completificate as	Dual supply	±5	±15	
Supply voltage	Single supply	10	30	V
Operating free-air temperature, T _A	DI.	-40	85	°C

ABSOLUTE MAXIMUM RATINGS

	100x-1 -1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1
CONT. CONT.	UNIT
Supply voltage, V _{S-} to V _{S+}	33 V
Input voltage, V _I	± V _S
Differential input voltage, V _{ID}	± 4 V
Output current, I _O	350 mA
Continuous power dissipation	See Dissipation Ratings Table
Maximum junction temperature, T _J	150°C
Maximum junction temperature, continuous operation, long term reliability, T _J ⁽²⁾	125°C
Storage temperature, T _{stg}	-65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	300°C
ESD ratings:	WWW. OOY.COM TW
НВМ	2000
CDM	1500
MAN ON WWW. CONT. CO. T.M.	150

The absolute maximum ratings under any condition is limited by the constraints of the silicon process. Stresses above these ratings may (1) cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

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The maximum junction temperature for continuous operation is limited by package constraints. Operation above this temperature may result in reduced reliability and/or lifetime of the device.



VI.	COM	WWW	TYP	$C_{O_{2a}}$	0	VER TEMP	ERATURE		
PARAMETER	TEST CONDITION	ons	25°C	25°C	0°C to 70°C	-40°C to 85°C	UNIT	MIN/TYP/ MAX	
AC PERFORMANCE	N. Jan.		M.In.	=1 C	Mr.	XX			
TITY WY	$G = 1$, $R_F = 1.1 \text{ k}\Omega$, $V_O = 200$	mV _{PP}	135	2.	$o_{M,J}$				
Small-signal bandwidth, -3 dB	G = 2, $R_F = 909 \Omega$, $V_O = 200 r$	mV _{PP}	145	J.Von	,]		
Silian-signal bandwidth, -5 db	$G = 5$, $R_F = 715 \Omega$, $V_O = 200 r$	mV _{PP}	160	051	COMr.	TAN .	MHz	TYP	
WIN W	G = 10, $R_F = 604 \Omega$, $V_O = 200$	mV_{PP}	145	100 2.	CON		IVII IZ	111	
0.1 dB bandwidth flatness	$G = 2$, $R_F = 909 \Omega$, $V_O = 200 r$	mV _{PP}	50	. 4005		WT]		
Large-signal bandwidth	$G = 5$, $R_F = 715 \Omega$, $V_O = 5 V_P$	P	150	1.1	o CO	Ar.			
Slew rate (25% to 75% level)	$G = 2$, $V_0 = 10$ -V step, $R_F = 90$	$G = 2$, $V_0 = 10$ -V step, $R_F = 909 Ω$		N.1U	- 00	$M_{r_{I}}$	-√ V/μs	TYP	
Siew rate (25% to 15% level)	G = 5, V_O = 20-V step, R_F = 715 Ω		5700	110	01.0	TIME	ν/μο	111	
Rise and fall time	$G = 2$, $V_O = 5 - V_{PP}$, $R_F = 909 \Omega$		5	111	agy.C	ON-	ns	TYP	
Settling time to 0.1%	$G = -2$, $V_O = 2 V_{PP}$ step	M.I.	42		No -	COM.	ns	TYP	
Settling time to 0.01% Harmonic distortion	$G = -2$, $V_O = 2$ V_{PP} step	OMITW	72		100%	COM	TV	• • • •	
~11003. W.IV	W 100 2.	$R_L = 100\Omega$	66		1.700	- 001	1.1		
2nd Harmonic distortion	G = 2, $R_F = 909 \Omega$,	$R_L = 1 k\Omega$	66	MAI	- ×1 100	N.C	T. V.	TVD	
M. Jan. COM.	$V_O = 2 V_{PP}$	$R_L = 100\Omega$	76		N.	W.CC	dBc	TYP	
3rd Harmonic distortion	I = 10 MH2	Harmonic distortion f = 10 MHz	$R_L = 1 k\Omega$	78		VV^{-1}	-1 C	OW.	
Input voltage noise	f > 10 kHz	TIM	2	- NN	-331	00 r.	nV / √Hz	TYP	
Noninverting input current noise	f > 10 kHz	NY.CO	13	1/1	11 41.	anny.	pA / √Hz	TYP	
Inverting input current noise	f > 10 kHz	COM	13		TWW.	·Ioo	pA / √Hz	TYP	
Differential gain	U. M.	NTSC	0.013%		-17	N.100 3	MOD		
Differential gain Differential phase	$G = 2,$ $R_L = 150 Ω,$ $R_F = 909 Ω$	PAL	0.011%		MW	100	Y.C.	TYP	
		NTSC	0.020°		- XIV	M.To	A CO		
Differential phase	The Marie	PAL	0.026°			-TVI.10		Mir	
ON WWW.	G = 2,	Ch 1 to 2	60			N 1	001.C	dB	
Crosstalk	$R_L = 100 \Omega$, f = 10 MHz	Ch 2 to 1	56	N	17	MM.	O.V.C		
DC PERFORMANCE	OMIT	VW.100	COM^{*}	-31		TINN	. I.O.	COMP.	
Transimpedance	$V_0 = \pm 7.5 \text{ V, Gain} = 1$	1007	850	350	300	300	kΩ	MIN	
Input offset voltage	CON W	WW.	0.9	3	4	4	mV	MAX	
Average offset voltage drift	down,		I CON	· ·	±10	±10	μV/°C	TYP	
Noninverting input bias current	· M.TW		4	15	20	20	μA	MAX	
Average bias current drift	V COM TW		N.Co	TI	±20	±20	μΑ/°C	TYP	
Inverting input bias current	$V_{CM} = 0 V$		3.5	15	20	20	μA	MAX	
Average bias current drift	O. T.W.T.W		00 .	$OM_{i,j}$	±20	±20	μΑ/°C	TYP	
Input offset current	NY.COM TY		1.7	10	15	15	μA	MAX	
Average offset current drift	COMP		· N	CO_{Dx}	±20	±20	μΑ/°C	TYP	
INPUT CHARACTERISTICS	100 r. COW. I.A.	- 11	N.100 -	- col	1.1	ſ	- TAN V	1.Ing	
Common-mode input range	WT. Co. TW	MAN	±13.6	±13.3	±13	±13	V	MIN	
Common-mode rejection ratio	V _{CM} = ±10 V	WW	78	68	65	65	dB	MIN	
Noninverting input resistance	1100 M.I.	**	1.3	10	Mr.	- «T	ΜΩ	TYP	
Noninverting input capacitance	100 Y.C TW	W	0.1	01.0			pF	TYP	
Inverting input resistance	MIN'T COM	N XX	30	any.	OF T	TW	Ω	TYP	
Inverting input capacitance	TW.100 COM.		1.4	No.	CO_{N_I}	, L	pF	TYP	

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ELECTRICAL CHARACTERISTICS (continued)

	COM	TYP	OVER TEMPERATURE				
PARAMETER	TEST CONDITIONS	25°C	25°C	0°C to 70°C	-40°C to 85°C	UNIT	MIN/TYP
OUTPUT CHARACTERISTICS	M.In. COM.	IN N. Inc	-1 CC)Mr.	***		
Output valtage auding	$R_L = 1 k\Omega$	±13.2	±12.8	±12.5	±12.5	V	MIN
Output voltage swing	$R_L = 100 \Omega$	±12.5	±12.1	±11.8	±11.8	V	IVIIIN
Output current (sourcing)	$R_L = 40 \Omega$	280	225	200	200	mA	MIN
Output current (sinking)	$R_L = 40 \Omega$	250	200	175	175	mA	MIN
Output impedance	f = 1 MHz, Closed loop	0.06	- 1005		NT	Ω	TYP
POWER SUPPLY	COM.	WWW	1.1	V CO	Mr.		
Specified operating voltage	M. 100x. CONT.	±15	±16	±16	±16	V	MAX
Maximum quiescent current	Per channel	9.5	10.5	11	11	mA	MAX
Minimum quiescent current	Per channel	9.5	8.5	8	8	mA	MIN
Power supply rejection (+PSRR)	V _{S+} = 15.5 V to 14.5 V, V _{S-} = 15 V	75	70	65	65	dB	MIN
Power supply rejection (-PSRR)	$V_{S+} = 15 \text{ V}, V_{S-} = -15.5 \text{ V} \text{ to } -14.5 \text{ V}$	73	68	65	65	dB	MIN
POWER-DOWN CHARACTERISTIC	CS (THS3096 ONLY)		MIN	007	1.Com	TVV.	
DEE voltoge renge(1)	W. 100 COM	V _{S+} - 4		1.700	-1 COD	1. 1	MAX
REF voltage range ⁽¹⁾	WW. 100X.C	V _{S-}	111	- 10°	7.0	V	MIN
Power down voltage level(1)	Enable	PD ≥ REF + 2	WW	A4	N.CC	V	MIN
Power-down voltage level ⁽¹⁾	Disable	<u>PD</u> ≤ REF + 0.8	-11	M.1.	*1 C!		MAX
Power-down quiescent current	<u>PD</u> = 0V	500	700	800	800	μΑ	MAX
WWW.	V _{PD} = 0 V, REF = 0 V,	11	15	20	20		MAX
V _{PD} quiescent current	V _{PD} = 3.3 V, REF = 0 V	11	15	20	20	μА	IVIAX
Turnon time delay	90% of final value	60		1	$0.100 \mathrm{p}$	Man	TVD
Turnoff time delay	10% of final value	150		- AI W	~ ~ ~ ~	μs	TYP

For detailed information on th behavior of the powerdown circuit, see the Powerdown and Powerdown Reference sections in the WWW.100Y.COM WWW.100Y.COM Application Information of this data sheet.

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N. IV.	COM	WW	TYP	CO_{h}	ov	ER TEMPE	RATURE	
PARAMETER	TEST CON	IDITIONS	25°C	25°C	0°C to 70°C	-40°C to 85°C	UNIT	MIN/TYP/ MAX
AC PERFORMANCE	COM	T 1	MM.Io.	- 57 C.)Mr.	X		
	$G = 1$, $R_F = 1.1 \text{ k}\Omega$, V_C	$_{\rm O}$ = 200 mV _{PP}	125	0x.	$o_{M,T}$			
Small-signal bandwidth, -3 dB	G = 2, R_F = 909 Ω , V_O	= 200 mV _{PP}	140	on Y.C	, , ,			
Small-signal bandwidth, -5 db	$G = 5, R_F = 715 \Omega, V_O$	= 200 mV _{PP}	145		CO_{Mr} .		MHz	TYP
The William	$G = 10, R_F = 604 \Omega, V$	$_{\rm O}$ = 200 mV _{PP}	135	700 7.	Mon		IVII IZ	
0.1 dB bandwidth flatness	G = 2, $R_F = 909 \Omega$, V_O	$= 200 \text{ mV}_{PP}$	42	- 1007		WIT		
Large-signal bandwidth	$G = 2, R_F = 909 \Omega, V_0$	$_{\rm O}$ = 5 $V_{\rm PP}$	125	V. 1	A CO			
Slew rate (25% to 75% level)	$G = 2$, $V_0 = 5$ -V step, F	$R_F = 909 \Omega$	1050	$\sqrt{100}$	- 00	Mir	√ V/µs	TYP
olew rate (20% to 70% level)	G = 5, V_O = 5-V step, R_F = 715 Ω		1350	110	07.0	TIME	ν/μ3	
Rise and fall time	G = 2, V_O = 5-V step, R_F = 909 Ω		5	1111.2	acv.C	On-	ns	TYP
Settling time to 0.1%	$G = -2$, $V_O = 2 V_{PP}$ ste	р	35		100	-OM-,	ns	TYP
Settling time to 0.01%	$G = -2$, $V_O = 2$ V_{PP} step		73	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	100 X.	Ma		
Harmonic distortion	WWW.	CORP	4	MIN	-007	CO	W	
2nd Harmonic distortion	G = 2,	$R_L = 100\Omega$	64		N'In	of CON	L. Z	
1001	$R_F = 909 \Omega$,	$R_L = 1 k\Omega$	67	111	-N 100	1.	dBc TYF	TYP
3rd Harmonic distortion	$V_O = 2 V_{PP}$, f = 10 MHz	$R_L = 100\Omega$	75	WW	- 10	OY.CO	WILL	
M.Ing. COM.	, William	$R_L = 1 k\Omega$	75		M_{N-1}	SJ C)Mr.	J
Input voltage noise	f > 10 kHz	0_{J} . 0_{MJ}	2	- 11	1	00 .	nV / √Hz	TYP
Noninverting input current noise	f > 10 kHz	any.Co	13	1	M	1007.	pA / √Hz	TYP
Inverting input current noise	f > 10 kHz	A COM	13		JWW	, I	pA / √Hz	TYP
Differential gain Differential phase	$G = 2,$ $R_{L} = 150 \Omega,$ $R_{F} = 909 \Omega$	NTSC	0.027%		1	1.100	COM	
		PAL	0.025%		Al A.	A 100		TYP
		NTSC	0.04°		WW	111.5	A COR	
M. 100 J. COW.T.	2 3	PAL	0.05°			IN Ju	- c0	MI
Crosstalk	G = 2, $R_L = 100 \Omega$,	Ch 1 to 2	60	N	W.	- TAN 1	101.	dB
MANN. TO OA. COM.	f = 10 kHz	Ch 2 to 1	56	W		M. A.	OOY.C.	
DC PERFORMANCE		WW.IV	CO_{M}	- XI		MW.	~ C	OM.
Transimpedance	$V_0 = \pm 2.5 \text{ V, Gain} = 1$	1007	700	250	200	200	kΩ	MIN
Input offset voltage	WT		0.3	2	3	3	mV	MAX
Average offset voltage drift	7		J CON	1	±10	±10	μV/°C	TYP
Noninverting input bias current	MILM		2	15	20	20	μA	MAX
Average bias current drift	V _{CM} = 0 V		N.C.	TILL	±20	±20	μΑ/°C	TYP
Inverting input bias current	VCM = 0 V		5	15	20	20	μA	MAX
Average bias current drift	OWIL		100 .	OM_{ij}	±20	±20	μΑ/°C	TYP
Input offset current	.Co.		11.	10	15	15	μA	MAX
Average offset current drift	CONT		N. Co.	Co_{D_2}	±20	±20	μΑ/°C	TYP
INPUT CHARACTERISTICS	COMIT		N.100	COL	1.1		WW	Too
Common-mode input range	IV.C	M. A.	±3.6	±3.3	±3	±3	V	MIN
Common-mode rejection ratio	$V_{CM} = \pm 2.0 \text{ V}, V_{O} = 0 \text{ V}$	V VV	66	60	57	57	dB	MIN
Noninverting input resistance	on. COM:	st == t	1.1	- C	DINT.	- - 5.1	ΜΩ	TYP
Noninverting input capacitance	LIM- YOU	n N	1.2	101.	$-\infty$	41	pF	TYP
Inverting input resistance	LOON.COM.	W v	32	00X.	7	W	Ω	TYP
Inverting input capacitance	In COM.	L .	1.5	LU	CO_{Mr}		pF	TYP

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ELECTRICAL CHARACTERISTICS (continued)

	Tr CONT.	TYP	OVER TEMPERATURE					
PARAMETER	TEST CONDITIONS	25°C	25°C	0°C to 70°C	-40°C to 85°C	UNIT	MIN/TYP/ MAX	
OUTPUT CHARACTERISTICS	N. Ion COM.	M.Io.	*1 CC	DMr.	*X			
Output voltage ewing	$R_L = 1 \text{ k}\Omega$	±3.4	±3.1	±2.8	±2.8	- V N		MIN
Output voltage swing	$R_L = 100 \Omega$	±3.1	±2.7	±2.5	±2.5		IVIIIN	
Output current (sourcing)	R _L = 10 Ω	200	160	140	140	mA	MIN	
Output current (sinking)	R _L = 10 Ω	180	150	125	125	mA	MIN	
Output impedance	f = 1 MHz, Closed loop	0.09	- 100		WILL	Ω	TYP	
POWER SUPPLY	TWW.Inc. COM.	TWW.	.10	V CO	MI			
Specified operating voltage	M. 1003. COM: I.A.	±5	±4.5	±4.5	±4.5	V	MAX	
Maximum quiescent current	Per channel	8.2	9	9.5	9.5	mA	MAX	
Minimum quiescent current		8.2	7	6.5	6.5	mA	MIN	
Power supply rejection (+PSRR)	$V_{S+} = 5.5 \text{ V to } 4.5 \text{ V}, V_{S-} = -5 \text{ V}$	73	68	63	63	dB	MIN	
Power supply rejection (-PSRR)	$V_{S+} = 5 \text{ V}, V_{S-} = -4.5 \text{ V to } 5.5 \text{ V}$	71	65	60	60	dB	MIN	
POWER-DOWN CHARACTERISTIC	CS (THS3096 ONLY)				1.Com	W		
DEE(1)	100 CON	V _{S+} – 4	- 17.7	1.700	-1 (0)	1. ×	MAX	
REF voltage range ⁽¹⁾	77 1007.00	V _{S-}	11 4.	-x1 100	7.0	V	MIN	
D	Enable	PD ≥ REF + 2	WW	44.	W.Co	V	MIN	
Power-down voltage level ⁽¹⁾	Disable	<u>PD</u> ≤ REF + 0.8		M.M.	-7 C	M.r.	MAX	
Power-down quiescent current	PD = 0V	300	500	600	600	μA	MAX	
V guigacent current	V _{PD} = 0 V, REF = 0 V,	11	15	20	20		MAN	
V _{PD} quiescent current	V _{PD} = 3.3 V, REF = 0 V	11	15	20	20	μA	MAX	
Turnon time delay	90% of final value	60		1	N 100 x	Vion	TVD	
Turnoff time delay	10% of final value	150		WIKE	~ ~ ~ ~ ~	μs	TYP	

For detailed information on th behavior of the powerdown circuit, see the Powerdown and Powerdown Reference sections in the Application Information of this data sheet.

TYPICAL CHARACTERISTICS

TABLE OF GRAPHS

TYPICA	AL CHARACTERISTICS	
TABLE OF GRAPHS		
WWW. 100Y. CONT.TW	MI TOOK CON THE	FIGURE
±15-V graphs	WWW.100Y.CO.T.TW	1007.
Noninverting frequency response	WWW. TOWN WWW	1, 2
Inverting frequency response	M. Ing. COM.	3 CO
0.1 dB flatness	W. 1001. COW.TW	4
Noninverting frequency response	MM 100X'CO ILM MA	5
Inverting frequency response	MAN ON COMP	6
Frequency response capacitive load	W. M. M. COM.	7
Recommended R _{ISO}	vs Capacitive load	8
2nd Harmonic distortion	vs Frequency	9, 11
3rd Harmonic distortion	vs Frequency	10, 12
Slew rate	vs Output voltage step	13, 14, 15
Noise	vs Frequency	16
Settling time	TW WWW. COY. CO. TW	17, 18
Quiescent current	vs Supply voltage	19
Output voltage	vs Load resistance	20
Input bias and offset current	vs Case temperature	21
Input offset voltage	vs Case temperature	22



TYPICAL CHARACTERISTICS (continued)

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Transimpedance	vs Frequency	2
Rejection ratio	vs Frequency	24
Noninverting small signal transient response	LIV WILLIAM TOWN.	25
Inverting large signal transient response	CTW WWW. 100Y.Co. TIT	26,
Overdrive recovery time	M. M. M. COM.	28
Differential gain	vs Number of loads	29
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Closed loop output impedance	vs Frequency	31
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Power-down quiescent current	vs Supply voltage	33
Turnon and turnoff time delay	Y.C. TAN MILL 1001.0	34

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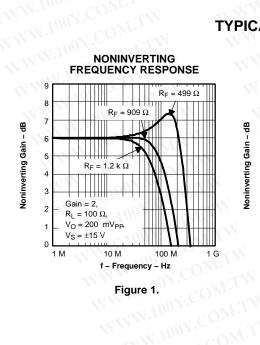
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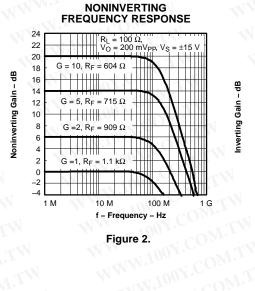
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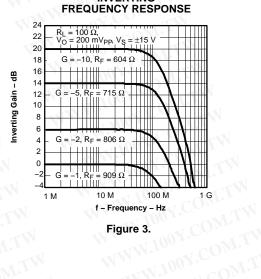
TYPICAL CHARACTERISTICS (±15 V)







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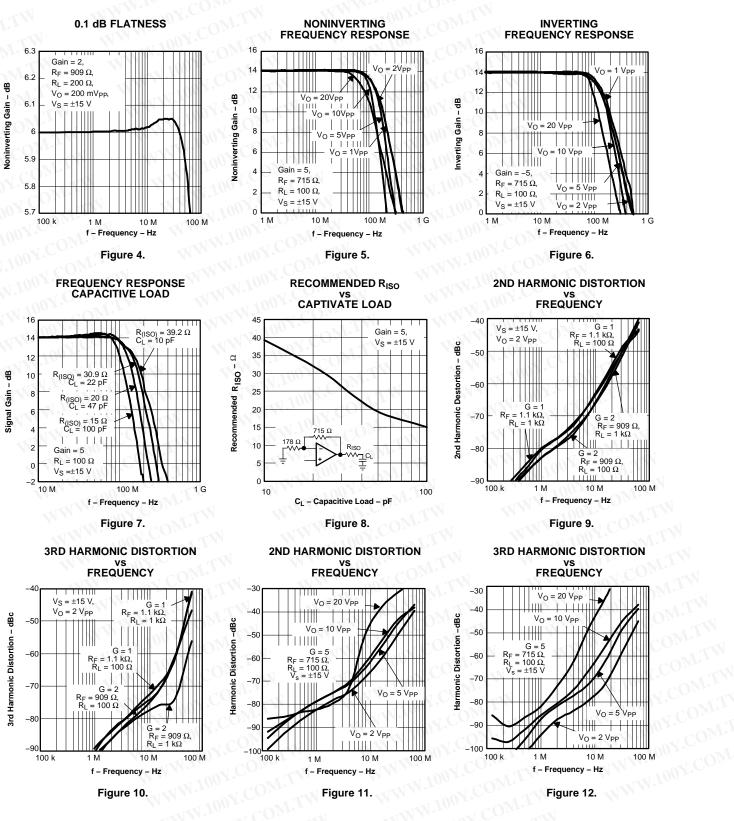
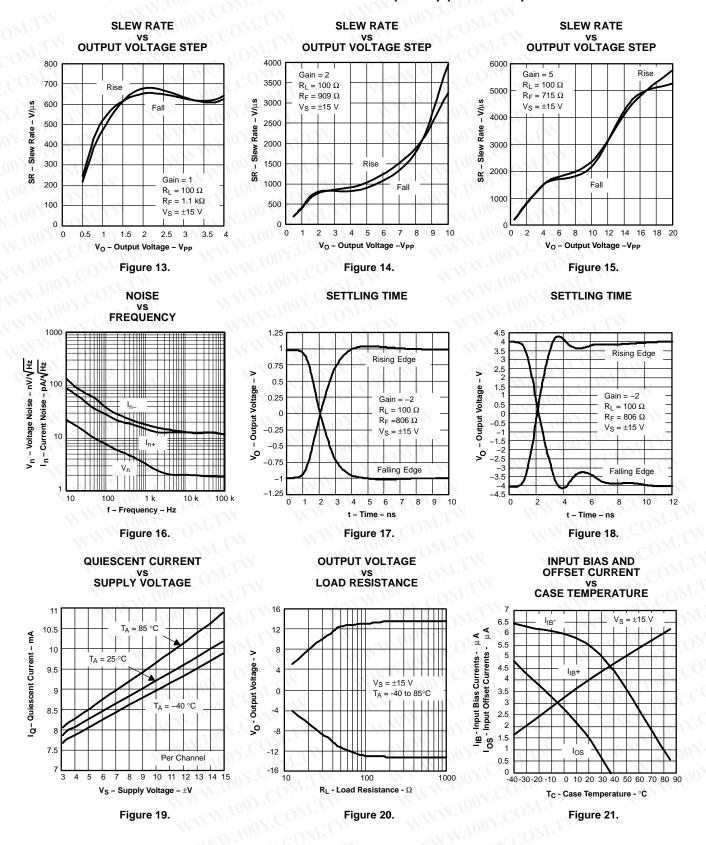


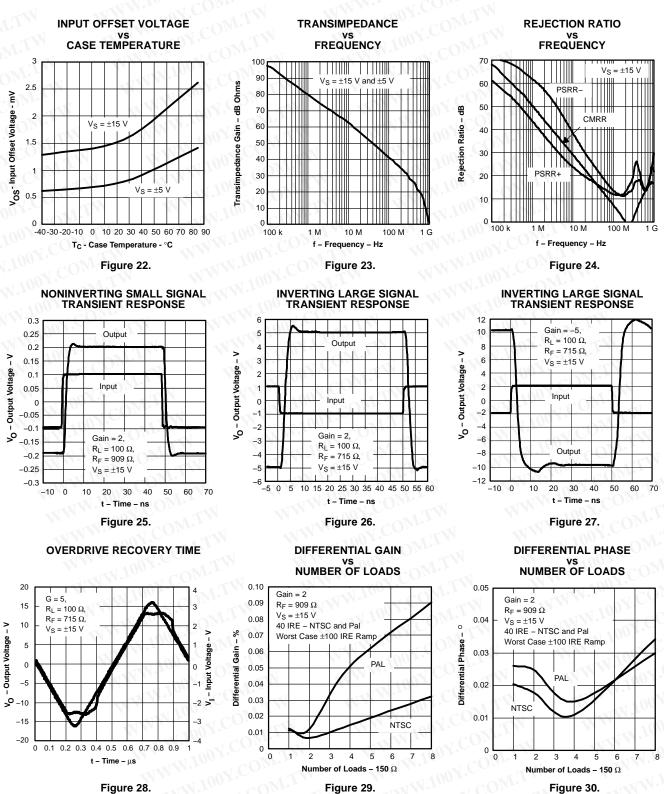
Figure 10.

Figure 11.

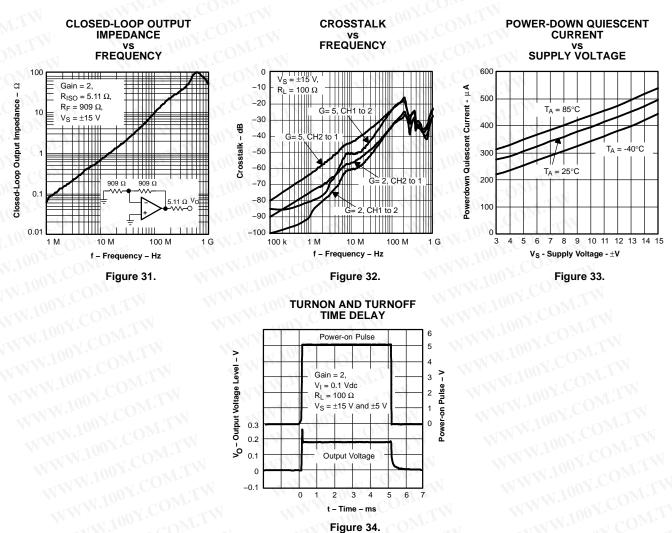




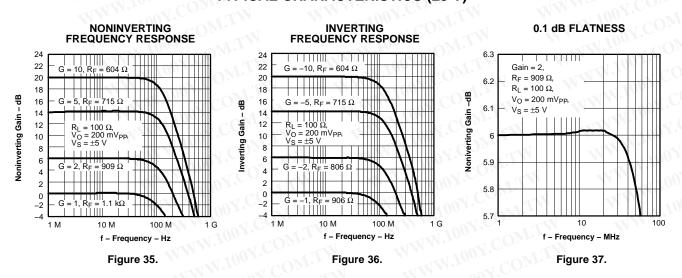




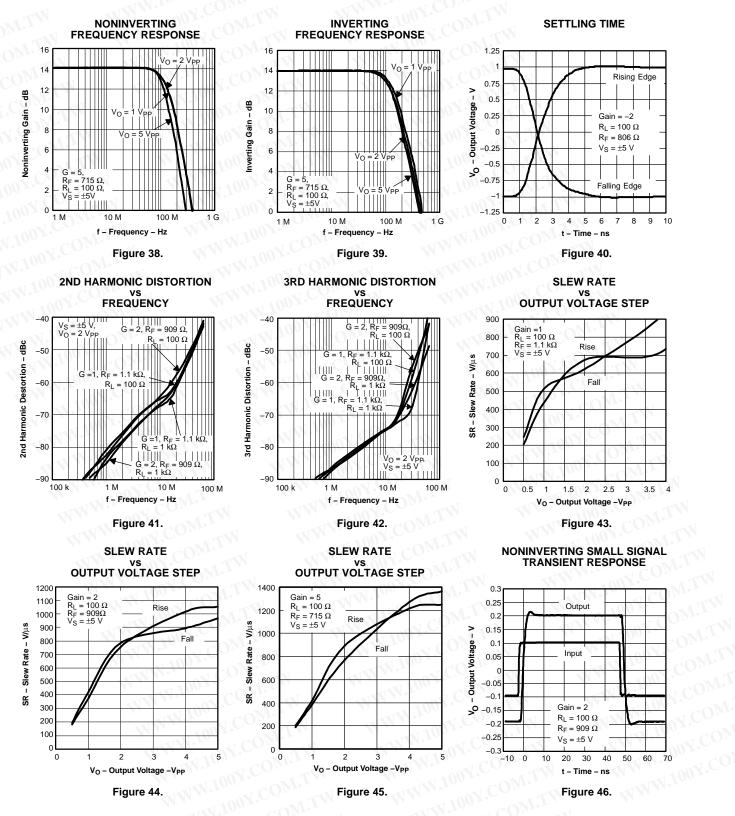




TYPICAL CHARACTERISTICS (±5 V)









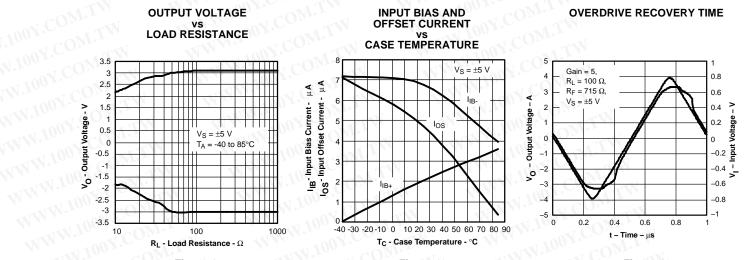
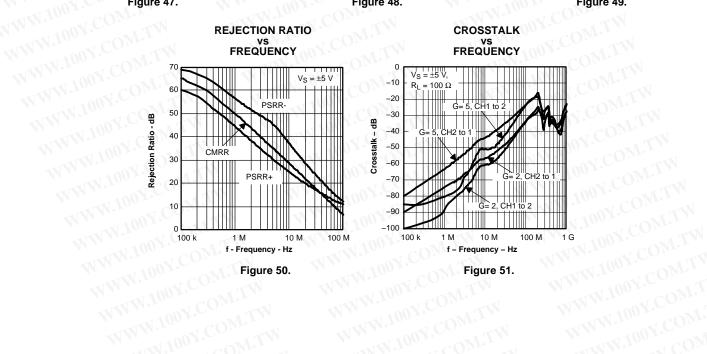


Figure 49. Figure 47. Figure 48.



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APPLICATION INFORMATION

WIDEBAND, NONINVERTING OPERATION

The THS3092/6 are unity gain stable 135-MHz current-feedback operational amplifiers, designed to operate from a \pm 5-V to \pm 15-V power supply.

Figure 52 shows the THS3092 in a noninverting gain of 2-V/V configuration typically used to generate the performance curves. Most of the curves were characterized using signal sources with $50-\Omega$ source impedance, and with measurement equipment presenting a $50-\Omega$ load impedance.

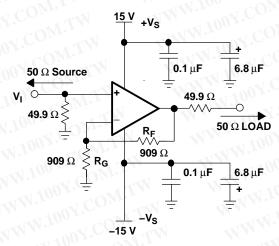


Figure 52. Wideband, Noninverting Gain Configuration

Current-feedback amplifiers are highly dependent on

the feedback resistor R_F for maximum performance and stability. Table 1 shows the optimal gain setting resistors R_F and R_G at different gains to give maximum bandwidth with minimal peaking in the frequency response. Higher bandwidths can be achieved, at the expense of added peaking in the frequency response, by using even lower values for R_F . Conversely, increasing R_F decreases the bandwidth, but stability is improved.

Table 1. Recommended Resistor Values for Optimum Frequency Response

THS3092 and THS3096 $\rm R_F$ and $\rm R_G$ values for minimal peaking with R _L = 100 Ω						
GAIN (V/V)	SUPPLY VOLTAGE (V)	$R_{G}(\Omega)$	R _F (Ω)			
1	±15	1.1.7.	1.1 k			
N '	±5	1 T-1	1.1 k			
W 2	±15	909	909			
	±5	909	909			
5	±15	178	715			
3	±5	178	715			
10	±15	66.5	604			
10	±5	66.5	604			
-1	±15 and ±5	909	909			
-2	±15 and ±5	402	806			
-5	±15 and ±5	143	715			
-10	±15 and ±5	60.4	604			

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WIDEBAND, INVERTING OPERATION

Figure 53 shows the THS3092 in a typical inverting gain configuration where the input and output impedances and signal gain from Figure 52 are retained in an inverting circuit configuration.

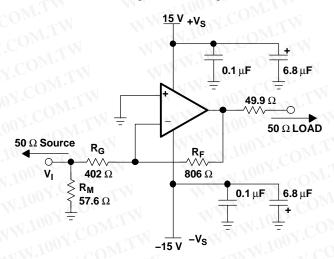


Figure 53. Wideband, Inverting Gain Configuration

SINGLE SUPPLY OPERATION

The THS3092/6 have the capability to operate from a single supply voltage ranging from 10 V to 30 V. When operating from a single power supply, biasing the input and output at mid-supply allows for the maximum output voltage swing. The circuits shown in Figure 54 shows inverting and noninverting amplifiers configured for single supply operations.

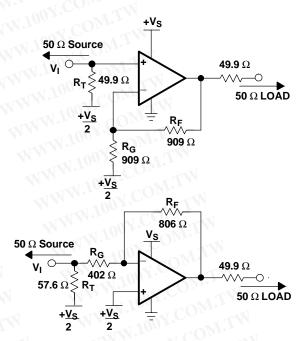


Figure 54. DC-Coupled, Single-Supply Operation

VDSL Driver Circuit

The THS3092 and THS3096 have the ability to drive over 200 mA of current with very high voltage swings. Using these amplifiers coupled with the very high slew rate, low distortion, and low noise required in VDSL applications, makes for a perfect match. In VDSL systems where the receive signal is critical, the use of a low transformer ratio is necessary. With this low ratio, the output swing required from the line driver amplifier must increase, especially when driving the VDSL's full 14.5-dBm power onto the line. The line driver's low distortion and noise is critical for the VDSL as the receive bands are intertwined with the transmit frequency bands up to the 12-MHz VDSL limit

Figure 55 shows a traditional hybrid connection approach for achieving the 14.5-dBm line power utilizing a 1:1 transformer. Looking at the input to the amplifiers shows a low-pass filter consisting of two separate capacitors to ground. There is an argument that since the signal coming out of the DAC is fully-differential then a single capacitor (10 pF in this case) is perfectly acceptable. The problem with this idea is that many DACs have common-mode energy due to images around the sampling frequency which must be filtered before reaching the amplifier. An amplifier simply amplifies its input-including the DAC's images at high frequencies-and pass it through to the transformer and ultimately to the line. possibly causing the system to fail EMC compliance. single capacitor does not remove



common-mode images, it only removes the differential signal images. However, two separate filter capacitors filter both the common-mode signals and the differential-mode signals. Be sure to place the ground connection point of the capacitors next to each other, and then tie a single ground point at the middle of this trace.

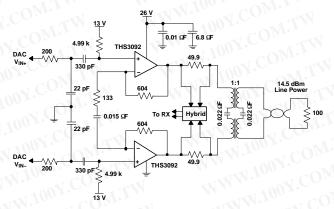


Figure 55.

Additionally, level shifting must be done to center the common-mode voltage appearing at the amplifier's noninverting input to optimally the midpoint of the power supply. As a side benefit of the ac-coupling/level shifter, a simple high pass filter is formed. This is generally a good idea for VDSL systems where the transmit band is typically above 1 MHz, but can be as low as 25 kHz.

One of the concerns about any DSL line driver is the power dissipation. One of the most common ways to reduce power is by using active termination, aka synthesized impedance. Refer to TI Application Note SLOA100 for more information on active termination. The drawback to active termination is the received signal is reduced by the same synthesis factor utilized in the system. Due to the very high attenuation of the line at up to 12 MHz, the receive signal can be severely diminished. Thus, the use of active termination should be kept to modest levels at best. Figure 56 shows an example of utilizing a simple active termination scheme with a synthesis factor of 2 to achieve the same line power, but with a reduced power supply voltage that ultimately saves power in the system.

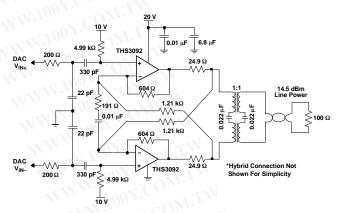


Figure 56.

Video Distribution

The wide bandwidth, high slew rate, and high output drive current of the THS3092/6 matches the demands for video distribution for delivering video signals down multiple cables. To ensure high signal quality with minimal degradation of performance, a 0.1-dB gain flatness should be at least 7x the passband frequency to minimize group delay variations from the amplifier. A high slew rate minimizes distortion of the video signal, and supports component video and RGB video signals that require fast transition times and fast settling times for high signal quality.

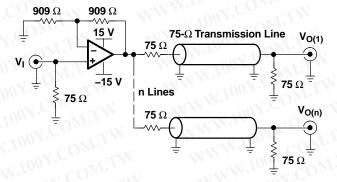


Figure 57. Video Distribution Amplifier Application

Driving Capacitive Loads

Applications such as FET line drivers can be highly capacitive and cause stability problems for high-speed amplifiers.

Figure 58 through Figure 63 show recommended methods for driving capacitive loads. The basic idea is to use a resistor or ferrite chip to isolate the phase shift at high frequency caused by the capacitive load from the amplifier's feedback path. See Figure 58 for recommended resistor values versus capacitive load.



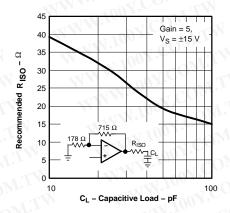


Figure 58. Recommended R_{ISO} vs Capacitive Load

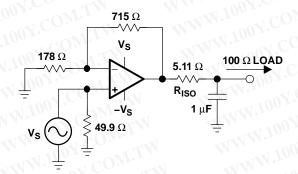


Figure 59.

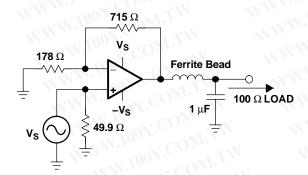


Figure 60.

Placing a small series resistor, $R_{\rm ISO}$, between the amplifier's output and the capacitive load, as shown in Figure 59, is an easy way of isolating the load capacitance.

Using a ferrite chip in place of $R_{\rm ISO},$ as shown in Figure 60, is another approach of isolating the output of the amplifier. The ferrite's impedance characteristic versus frequency is useful to maintain the low frequency load independence of the amplifier while isolating the phase shift caused by the capacitance at high frequency. Use a ferrite with similar impedance to $R_{\rm ISO},\,20~\Omega$ - $50~\Omega,$ at 100 MHz and low impedance at dc.

Figure 61 shows another method used to maintain the low frequency load independence of the amplifier while isolating the phase shift caused by the capacitance at high frequency. At low frequency, feedback is mainly from the load side of R_{ISO}. At high frequency, the feedback is mainly via the 27-pF capacitor. The resistor R_{IN} in series with the negative input is used to stabilize the amplifier and should be equal to the recommended value of R_F at unity gain. Replacing R_{IN} with a ferrite of similar impedance at about 100 MHz as shown in Figure 62 gives similar results with reduced dc offset and low frequency noise. (See the **ADDITIONAL** REFERENCE MATERIAL section for Expanding the usability of current-feedback amplifiers.)

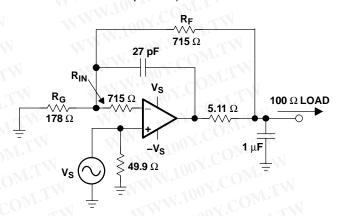


Figure 61.

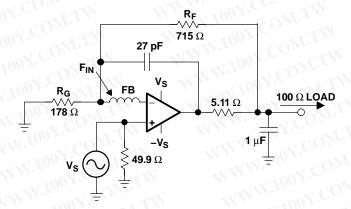


Figure 62.

Figure 63 is shown using two amplifiers in parallel to double the output drive current to larger capacitive loads. This technique is used when more output current is needed to charge and discharge the load faster like when driving large FET transistors.



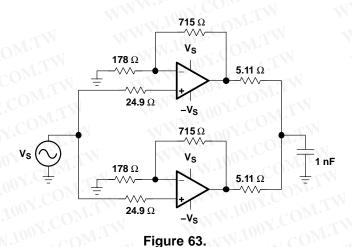


Figure 64 shows a push-pull FET driver circuit typical of ultrasound applications with isolation resistors to isolate the gate capacitance from the amplifier.

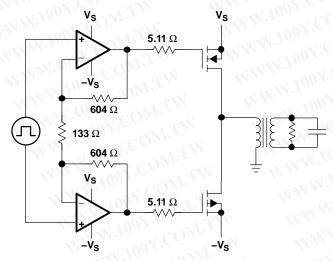


Figure 64. PowerFET Drive Circuit

SAVING POWER WITH POWER-DOWN FUNCTIONALITY AND SETTING THRESHOLD LEVELS WITH THE REFERENCE PIN

The THS3096 features a power-down pin (\overline{PD}) which lowers the quiescent current from 9.5 mA down to 500 μ A, ideal for reducing system power.

The power-down pin of the amplifier defaults to the positive supply voltage in the absence of an applied voltage, putting the amplifier in the power-on mode of operation. To turn off the amplifier in an effort to conserve power, the power-down pin can be driven towards the negative rail. The threshold voltages for power-on and power-down are relative to the supply

rails and are given in the specification tables. Above the *Enable Threshold Voltage*, the device is on. Below the *Disable Threshold Voltage*, the device is off. Behavior in between these threshold voltages is not specified.

Note that this power-down functionality is just that; the amplifier consumes less power in power-down mode. The power-down mode is not intended to provide a high-impedance output. In other words, the power-down functionality is not intended to allow use as a 3-state bus driver. When in power-down mode, the impedance looking back into the output of the amplifier is dominated by the feedback and gain setting resistors, but the output impedance of the device itself varies depending on the voltage applied to the outputs.

Figure 65 shows the total system output impedance which includes the amplifier output impedance in parallel with the feedback plus gain resistors, which cumulate to 2420 Ω . Figure 52 shows this circuit configuration for reference.

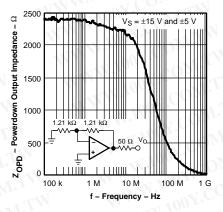


Figure 65. Power-down Output Impedance vs Frequency

As with most current feedback amplifiers, the internal architecture places some limitations on the system when in power-down mode. Most notably is the fact that the amplifier actually turns ON if there is a ±0.7 V or greater difference between the two input nodes (V+ and V-) of the amplifier. If this difference exceeds ±0.7 V, the output of the amplifier creates an output voltage equal to approximately $[(V+ - V-) - 0.7 V] \times Gain$. This also implies that if a voltage is applied to the output while in power-down the Vmode. node voltage is egual to $V_{O(applied)} \times R_G/(R_F + R_G)$. For low gain configurations and a large applied voltage at the output, the amplifier may actually turn ON due to aforementioned behavior.

The time delays associated with turning the device on



and off are specified as the time it takes for the amplifier to reach either 10% or 90% of the final output voltage. The time delays are in the order of microseconds because the amplifier moves in and out of the linear mode of operation in these transitions.

POWER-DOWN REFERENCE PIN OPERATION

In addition to the power-down pin, the THS3096 features a reference pin (REF) which allows the user to control the enable or disable power-down voltage levels applied to the \overline{PD} pin. In most split-supply applications, the reference pin is connected to ground. In either case, the user needs to be aware of voltage-level thresholds that apply to the power-down pin. The tables below show examples and illustrate the relationship between the reference voltage and the power-down thresholds. In the table, the threshold levels are derived by the following equations:

PD ≤ REF + 0.8 V for disable

PD ≥ REF + 2.0 V for enable

where the usable range at the REF pin is $V_{S-} \le V_{REF} \le (V_{S+} - 4 \ V)$.

The recommended mode of operation is to tie the REF pin to midrail, thus setting the enable/disable thresholds to V_{midrail} + 2 V and V_{midrail} + 0.8 V respectively.

Table 2. Power-Down Threshold Voltage Levels

SUPPLY VOLTAGE (V)	REFERENCE PIN VOLTAGE (V)	ENABLE LEVEL (V)	DISABLE LEVEL (V)			
±15, ±5	0.0	2.0	0.8			
±15	2.0	4.0 2.8				
±15	-2.0	0.0 -1.2				
±5	1.0	3.0	1.8			
±5	±5 –1.0		-0.2			
30	15	17	15.8			
10	5.0	7.0	5.8			

Note that if the REF pin is left unterminated, it will float to the positive rail and will fall outside of the recommended operating range given above $V_{S-} \leq V_{REF} \leq (V_{S+} - 4 \text{ V}).$ As a result, it will no longer serve as a reliable reference for the \overline{PD} pin, and the enable/disable thresholds given above will no longer apply. If the \overline{PD} pin is also left unterminated, it will also float to the positive rail and the device will be enabled. If balanced, split supplies are used $(\pm V_S)$ and the REF and \overline{PD} pins are grounded, the device will be disabled.

PRINTED-CIRCUIT BOARD LAYOUT TECHNIQUES FOR OPTIMAL PERFORMANCE

Achieving optimum performance with high frequency amplifier, like the THS3092/6, requires careful attention to board layout parasitic and external component types.

Recommendations that optimize performance include:

- Minimize parasitic capacitance to any ac ground for all of the signal I/O pins. Parasitic capacitance on the output and input pins can cause instability. To reduce unwanted capacitance, a window around the signal I/O pins should be opened in all of the ground and power planes around those pins. Otherwise, ground and power planes should be unbroken elsewhere on the board.
- Minimize the distance (< 0.25") from the power supply pins to high frequency 0.1-µF and 100-pF decoupling capacitors. At the device pins, the ground and power plane layout should not be in close proximity to the signal I/O pins. Avoid narrow power and ground traces to minimize inductance between the pins and the decoupling capacitors. The power supply connections should always be decoupled with these capacitors. Larger (6.8 µF or more) tantalum decoupling capacitors, effective at lower frequency, should also be used on the main supply pins. These may be placed somewhat farther from the device and may be shared among several devices in the same area of the PC board.</p>
- Careful selection and placement of external the high frequency components preserve performance of the THS3092/6. Resistors should be a very low reactance type. Surface-mount resistors work best and allow a tighter overall layout. Again, keep their leads and PC board trace length as short as possible. Never use wirebound type resistors in a high frequency application. Since the output pin and inverting input pins are the most sensitive to parasitic capacitance, always position the feedback and series output resistors, if any, as close as possible to the inverting input pins and output pins. Other network components, such as input termination resistors, should be placed close to the gain-setting resistors. Even with a low parasitic capacitance shunting the external resistors, excessively high resistor values can create significant time constants that can degrade performance. Good axial metal-film surface-mount resistors have approximately 0.2 pF in shunt with the resistor. For resistor values > 2.0 k Ω , this parasitic capacitance can add a pole and/or a zero that can effect circuit operation. Keep resistor values as low as possible, consistent with load driving considerations.



- Connections to other wideband devices on the board may be made with short direct traces or through onboard transmission lines. For short connections, consider the trace and the input to the next device as a lumped capacitive load. Relatively wide traces (50 mils to 100 mils) should be used, preferably with ground and power planes opened up around them. Estimate the total capacitive load and determine if isolation resistors on the outputs are necessary. Low parasitic capacitive loads (< 4 pF) may not need an R_S since the THS3092/6 are nominally compensated to operate with a 2-pF parasitic load. Higher parasitic capacitive loads without an RS are allowed as the signal gain increases (increasing the unloaded phase margin). If a long trace is required, and the 6-dB signal loss intrinsic to a doubly-terminated transmission line is acceptable, implement a matched impedance transmission line using microstrip or stripline techniques (consult an ECL design handbook for microstrip and stripline layout techniques). A $50-\Omega$ environment is not necessary onboard, and a higher impedance environment in fact, improves distortion as shown in the distortion versus load plots. With a characteristic board trace impedance based on board material and trace dimensions, a matching series resistor into the trace from the output of the THS3092/6 is used as well as a terminating shunt resistor at the input of the destination device. Remember also that the terminating impedance is the parallel combination of the shunt resistor and the input impedance of the destination device: this total effective impedance should be set to match the trace impedance. If the 6-dB attenuation of a doubly terminated transmission line is unacceptable, a long trace can be series-terminated at the source end only. Treat the trace as a capacitive load in this case. This does not preserve signal integrity as well as a doubly-terminated line. If the input impedance of the destination device is low, there is some signal attenuation due to the voltage divider formed by the series output into the terminating impedance.
- Socketing a high speed part like the THS3092/6 are not recommended. The additional lead length and pin-to-pin capacitance introduced by the socket can create an extremely troublesome parasitic network which can make it almost impossible to achieve a smooth, stable frequency response. Best results are obtained by soldering the THS3092/6 parts directly onto the board.

PowerPAD™ DESIGN CONSIDERATIONS

The THS3092/6 are available in a thermally-enhanced PowerPAD family of packages. These packages are constructed using a downset

leadframe upon which the die is mounted [see Figure 66(a) and Figure 66(b)]. This arrangement results in the lead frame being exposed as a thermal pad on the underside of the package [see Figure 66(c)]. Because this thermal pad has direct thermal contact with the die, excellent thermal performance can be achieved by providing a good thermal path away from the thermal pad. Note that devices such as the THS3092/6 have no electrical connection between the PowerPAD and the die.

The PowerPAD package allows for both assembly and thermal management in one manufacturing operation. During the surface-mount solder operation (when the leads are being soldered), the thermal pad can also be soldered to a copper area underneath the package. Through the use of thermal paths within this copper area, heat can be conducted away from the package into either a ground plane or other heat dissipating device.

The PowerPAD package represents a breakthrough in combining the small area and ease of assembly of surface mount with the, heretofore, awkward mechanical methods of heatsinking.

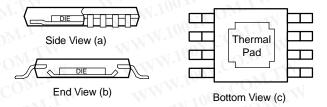


Figure 66. Views of Thermal Enhanced Package

Although there are many ways to properly heatsink the PowerPAD package, the following steps illustrate the recommended approach.

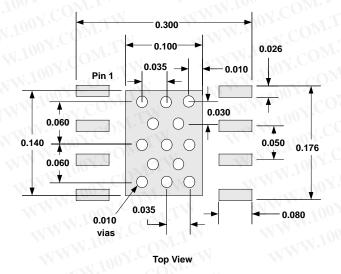


Figure 67. DDA PowerPAD PCB Etch and Via Pattern



PowerPAD™ LAYOUT CONSIDERATIONS

- PCB with a top side etch pattern as shown in Figure 67. There should be etch for the leads as well as etch for the thermal pad.
- Place 13 holes in the area of the thermal pad.
 These holes should be 10 mils in diameter. Keep them small so that solder wicking through the holes is not a problem during reflow.
- 3. Additional vias may be placed anywhere along the thermal plane outside of the thermal pad area. This helps dissipate the heat generated by the THS3092/6 IC. These additional vias may be larger than the 10-mil diameter vias directly under the thermal pad. They can be larger because they are not in the thermal pad area to be soldered so that wicking is not a problem.
- 4. Connect all holes to the internal ground plane. Note that the PowerPAD is electrically isolated from the silicon and all leads. Connecting the PowerPAD to any potential voltage such as V_S., is acceptable as there is no electrical connection to the silicon.
 - 5. When connecting these holes to the ground plane, do not use the typical web or spoke via connection methodology. Web connections have a high thermal resistance connection that is useful for slowing the heat transfer during soldering operations. This makes the soldering of vias that have plane connections easier. In this application, however, low thermal resistance is desired for the most efficient heat transfer. Therefore, the holes under the THS3092/6 PowerPAD package should make connection to the internal ground plane with a connection around complete entire circumference of the plated-through hole.
 - 6. The top-side solder mask should leave the terminals of the package and the thermal pad area with its 13 holes exposed. The bottom-side solder mask should cover the 13 holes of the thermal pad area. This prevents solder from being pulled away from the thermal pad area during the reflow process.
 - Apply solder paste to the exposed thermal pad area and all of the IC terminals.
 - 8. With these preparatory steps in place, the IC is simply placed in position and run through the solder reflow operation as any standard surface-mount component. This results in a part that is properly installed.

POWER DISSIPATION AND THERMAL CONSIDERATIONS

The THS3092/6 incorporates automatic thermal shutoff protection. This protection circuitry shuts down the amplifier if the junction temperature exceeds approximately 160°C. When the junction temperature reduces to approximately 140°C, the amplifier turns on again. But, for maximum performance and reliability, the designer must take care to ensure that the design does not exceed a junction temperature of 125°C. Between 125°C and 150°C, damage does not occur, but the performance of the amplifier begins to degrade and long term reliability suffers. The thermal characteristics of the device are dictated by the package and the PC board. Maximum power dissipation for a given package can be calculated using the following formula.

$$P_{\text{Dmax}} = \frac{T_{\text{max}} - T_{\text{A}}}{\theta_{\text{JA}}}$$

where:

P_{Dmax} is the maximum power dissipation in the amplifier (W).

T_{max} is the absolute maximum junction temperature (°C).

T_A is the ambient temperature (°C).

$$\theta_{JA} = \theta_{JC} + \theta_{CA}$$

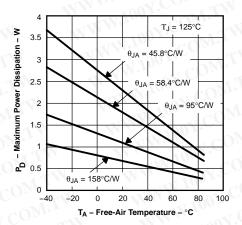
 θ_{JC} is the thermal coefficient from the silicon junctions to the case (°C/W).

 θ_{CA} is the thermal coefficient from the case to ambient air (°C/W).

For systems where heat dissipation is more critical, the THS3092 is offered in an 8-pin SOIC (DDA) with PowerPAD package, and the THS3096 is offered in a 14-pin TSSOP (PWP) with PowerPAD package for even better thermal performance. The thermal coefficient for the PowerPAD packages substantially improved over the traditional SOIC. Maximum power dissipation levels are depicted in the graph for the available packages. The data for the PowerPAD packages assume a board layout that follows the PowerPAD layout guidelines referenced above and detailed in the PowerPAD application note (literature number SLMA002). The following graph also illustrates the effect of not soldering the PowerPAD to a PCB. The thermal impedance increases substantially which may cause serious heat and performance issues. Be sure to always solder the PowerPAD to the PCB for optimum performance.

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Results are With No Air Flow and PCB Size = 3"x 3" $\theta J_A = 45.8^{\circ}$ C/W for 8-Pin SOIC w/PowerPAD (DDA) $\theta J_A = 58.4^{\circ}$ C/W for 8-Pin MSOP w/PowerPAD (DGN) $\theta J_A = 95^{\circ}$ C/W for 8-Pin SOIC High–K Test PCB (D) $\theta J_A = 158^{\circ}$ C/W for 8-Pin MSOP w/PowerPAD w/o Solder

Figure 68. Maximum Power Distribution vs Ambient Temperature

When determining whether or not the device satisfies the maximum power dissipation requirement, it is important to not only consider quiescent power dissipation, but also dynamic power dissipation. Often times, this is difficult to quantify because the signal pattern is inconsistent, but an estimate of the RMS power dissipation can provide visibility into a possible problem.

DESIGN TOOLS

Evaluation Fixtures, Spice Models, and Application Support

Texas Instruments is committed to providing its customers with the highest quality of applications support. To support this goal an evaluation board has been developed for the THS3092/6 operational amplifier. The board is easy to use, allowing for straightforward evaluation of the device. The evaluation board can be ordered through the Texas Instruments web site, www.ti.com, or through your local Texas Instruments sales representative.

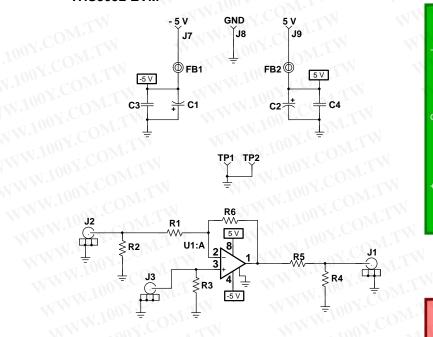
Computer simulation of circuit performance using is often useful when analyzing performance of analog circuits and systems. This is particularly true for video and RF-amplifier circuits where parasitic capacitance and inductance can have a major effect on circuit performance. A SPICE model for the THS3092/6 is available through either the Texas Instruments web site (www.ti.com) or as one model on a disk from the Texas Instruments Product Information Center (1-800-548-6132). The PIC is also available for design assistance and detailed product information at this number. These models do a good job of predicting small-signal ac and transient performance under a wide variety of operating conditions. They are not intended to model the distortion characteristics of the amplifier, nor do they attempt to distinguish between the package types in small-signal ac performance. Detailed information about what is and is not modeled is contained in the model file itself.

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THS3092 EVM



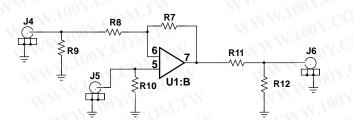


Figure 69. THS3092 EVM Schematic

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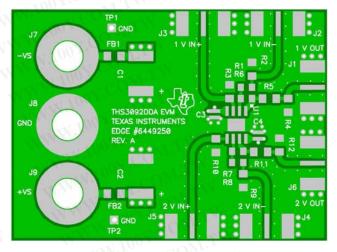


Figure 70. THS3092 EVM Board Layout (Top Layer)

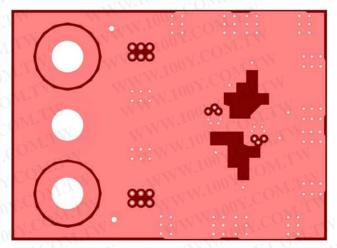


Figure 71. THS3092 EVM Board Layout WWW.100Y.COM.TW (Ground Plane)

W.100Y.COM.TW



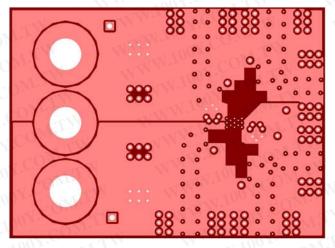


Figure 72. THS3092 EVM Board Layout (Power Plane)

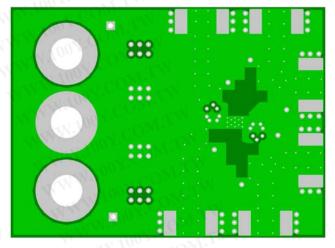


Figure 73. THS3092 EVM Board Layout (Bottom Layer)

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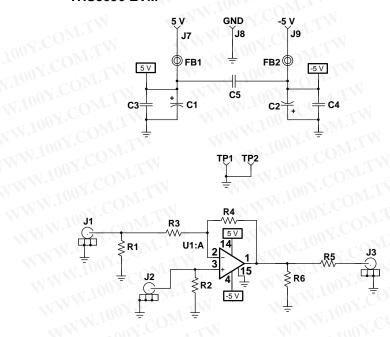
Table 3. THS3092 EVM Bill of Materials

ITEM	DESCRIPTION	SMD SIZE	092DGN EVM REFERENCE DESIGNATOR	PCB QTY	MANUFACTURER'S PART NUMBER ⁽¹⁾
111111111111111111111111111111111111111	Bead, Ferrite, 3 A, 80 Ω	1206	FB1, FB2	2	(Steward) HI1206N800R-00
2 .100	Cap. 22 μF, Tanatalum, 35 V, 10%	DIO	C1, C2	2	(AVX) TAJD685K035R
3	Cap. 0.1 µF, Ceramic, X7R, 16 V	0805	C3, C4	2	(AVX) 08055C104KAT2A
4	Resistor, 178 Ω, 1/8 W, 1%	0805	R1, R8	2	(KOA) RK73H2ALTD1780F
5	Resistor, 715 Ω, 1/8 W, 1%	0805	R6, R7	2	(KOA) RK73H2ALTD7150F
6	Open	1206	R4, R12	2	M. r. COM
7	Resistor, 0 Ω, 1/4 W, 1%	1206	R2, R9	2	(KOA) RK73Z2BLTD
8	Resistor, 49.9 Ω, 1/4 W, 1%	1206	R1, R5, R10, R11	4	(KOA) RK73H2BLTD49R9F
9	Connector, edge, SMA PCB jack	TINY	J1, J2, J3, J4, J5, J6	6	(Johnson) 142-0701-801
10	Jack, banana, 0.25" dia. hole	1	J7, J8, J9	3	(SPC) 813
11	Test point, black	MM	TP1, TP2	2	(Keystone) 5001
12	IC, THS3092	-317	U1 CO	1	(TI) THS3092DDA
13	Board, printed-circuit		111100 COM.	1	(TI) EDGE # 6446250 Rev. A

⁽¹⁾ The manufacturer's part numbers were used for test purposes only. WWW.100Y.COM.TW WWW.100Y.C



THS3096 EVM



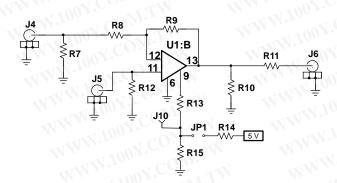


Figure 74. THS3096 EVM Schematic

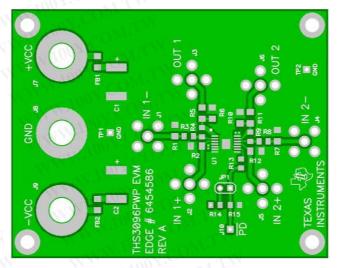


Figure 75. THS3096 EVM Board Layout (Top Layer)

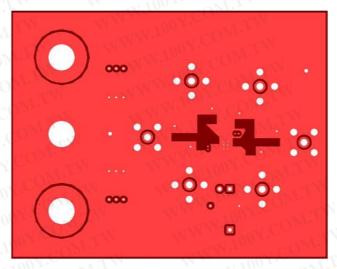


Figure 76. THS3096 EVM Board Layout (Ground Plane)

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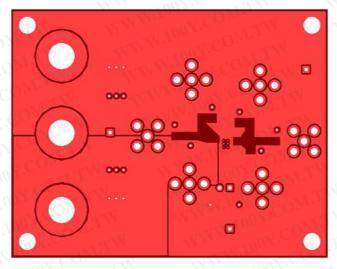


Figure 77. THS3096 EVM Board Layout

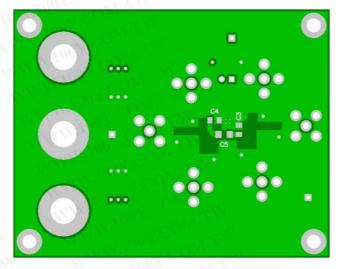


Figure 78. THS3096 EVM Board Layout (Bottom Layer)

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Table 4. THS3096 EVM Bill of Materials

1.100	CONT.	THS3	096PWP EVM	WWW	OV.CO
ITEM	DESCRIPTION	SMD SIZE	REFERENCE DESIGNATOR	PCB QTY	MANUFACTURER'S PART NUMBER
1 10	Bead, Ferrite, 3 A, 80 Ω	1206	FB1, FB2	2	(Steward) HI1206N800R-00
2	Cap. 22 µF, Tanatalum, 25 V, 10%	D 100	C1, C2	2	(AVX) TAJD226K025R
3	Cap. 0.1 µF, Ceramic, X7R, 50 V	0805	C3, C4	2	(AVX) 08055C104KAT2A
4	Cap. 0.1 µF, Ceramic, X7R, 50 V	1206	C5	1	(AVX) 12065C104KAT2A
5	Resistor, 100 Ω, 1/8W, 1%	0805	R13	1	(KOA) RK73H2ALTD1000F
6	Resistor, 178 Ω, 1/8 W, 1%	0805	R3, R8	2	(KOA) RK73H2ALTD1780F
7	Resistor, 715 Ω, 1/8 W, 1%	0805	R4, R9	2	(KOA) RK73H2ALTD7150F
8	Resistor, 20 kΩ, 1/8 W, 1%	0805	R14, R15	2	(KOA) RK73H2ALTD2002F
9	Open	1206	R6, R10	2	1100x. 21.37
10	Resistor, 0 Ω, 1/4 W, 1%	1206	R1, R7	2	(KOA) RK73Z2BLTD
11	Resistor, 49.9 Ω, 1/4 W, 1%	1206	R2, R5, R11, R12	4	(KOA) RK73H2BLTD49R9F
12	Header, 0.1" ctrs, 0.025" sq. pins	2 pos.	JP1	1	(Sullins) PZC36SAAN
13	Shunts	1	JP1	1	(Sullins) SSC02SYAN
14	Connector, SMA PCB jack		J1, J2, J3, J4, J5, J6	6	(Amphenol) 901-144-8RFX
15	Jack, banana, 0.25" dia. hole	N <	J7, J8, J9	3	(SPC) 813
16	Test point, red	-XX	J10	1	(Keystone) 5000
17	Test point, black		TP1, TP2	2	(Keystone) 5001
18	IC, THS3096	TW	U1	1.1	(TI) THS3096PWP
19	Board, printed-circuit		MAN WAY C	1.7	(TI) EDGE # 6454586 Rev. A



ADDITIONAL REFERENCE MATERIAL

- PowerPAD Made Easy, application brief (SLMA004)
- PowerPAD Thermally Enhanced Package, technical brief (SLMA002)
- Voltage Feedback vs Current Feedback Amplifiers, (SLVA051)
- Current Feedback Analysis and Compensation (SLOA021)
- Current Feedback Amplifiers: Review, Stability, and Application (SBOA081)
- Effect of Parasitic Capacitance in Op Amp Circuits (SLOA013)
- Expanding the Usability of Current-Feedback Amplifiers, by Randy Stephens, 3Q 2003 Analog Applications Journal www.ti.com/sc/analogapps).
- Active Output Impedance for ADSL Line Drivers (SLOA100) WWW.100 WWW.100Y.COM WWW.100Y.COM

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11-Apr-2013

PACKAGING INFORMATION

Orderable Device	Statu (1)	s Package Typ	e Package Drawing		Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Sample
THS3092D	ACTI	/E SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	3092	Sample
THS3092DDA	ACTI	/E SO PowerPA	D DDA	8	75	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	3092	Sample
THS3092DDAG3	ACTI	/E SO PowerPA	D DDA	8	75	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	3092	Sample
THS3092DDAR	ACTI	/E SO PowerPA	D DDA	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	3092	Sample
THS3092DDARG3	ACTI	/E SO PowerPA	D DDA	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	3092	Sample
THS3092DG4	ACTI	E SOIC	DIV	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	3092	Sample
THS3096D	ACTI	/E SOIC	CO'D'.	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	THS3096	Sample
THS3096DG4	ACTI	/E SOIC	Y.C.D.	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	THS3096	Sample
THS3096PWP	ACTI	/E HTSSOP	PWP	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	THS3096	Sample
THS3096PWPG4	ACTI	/E HTSSOP	PWP	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	THS3096	Sample

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



PACKAGE OPTION ADDENDUM

11-Apr-2013

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

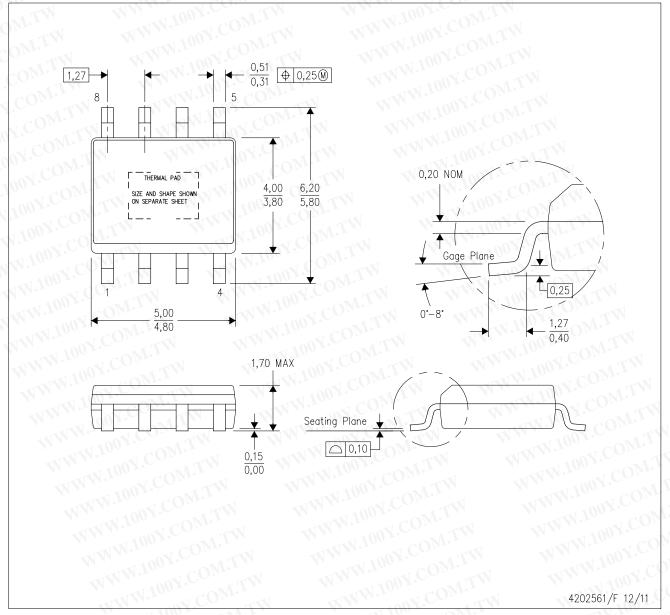
(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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DDA (R-PDSO-G8)

PowerPAD ™ PLASTIC SMALL-OUTLINE



NOTES:

- All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5-1994.
- This drawing is subject to change without notice.
- Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com http://www.ti.com.
- See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions. WWW.100Y.COM
- F. This package complies to JEDEC MS-012 variation BA

PowerPAD is a trademark of Texas Instruments.



DDA (R-PDSO-G8)

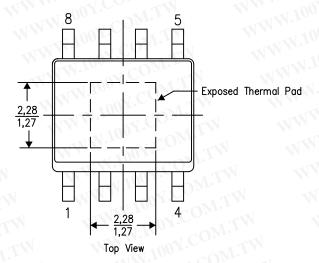
<u>P</u>owerPAD[™] PLASTIC SMALL OUTLINE

THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Exposed Thermal Pad Dimensions

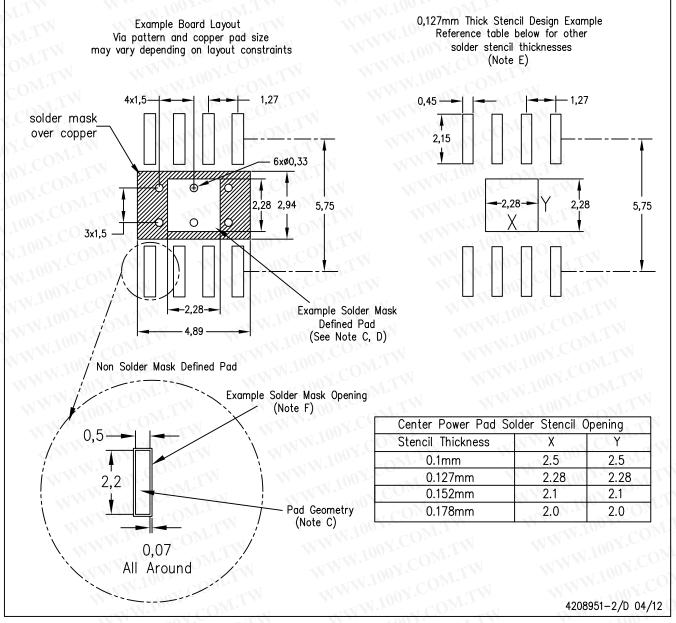
4206322-2/L 05/12 WWW.100Y.COM

NOTE: A. All linear dimensions are in millimeters



DDA (R-PDSO-G8)

PowerPAD™ PLASTIC SMALL OUTLINE



NOTES:

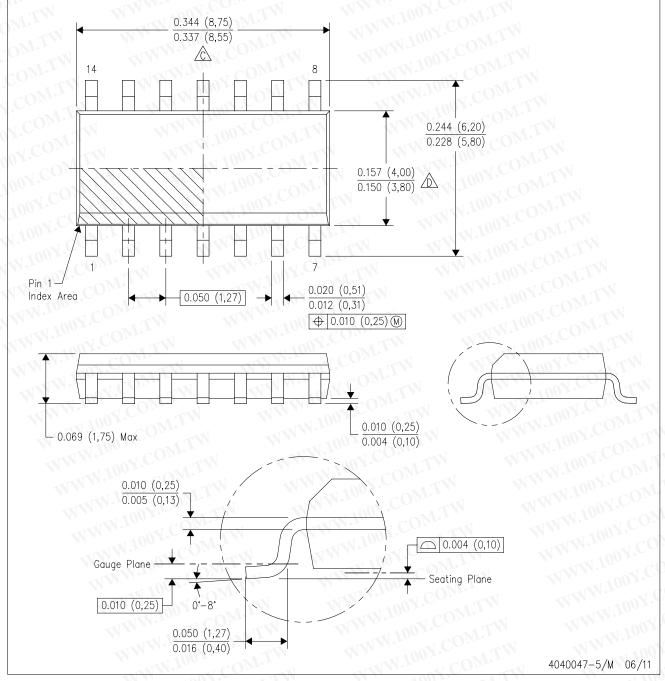
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
- F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

PowerPAD is a trademark of Texas Instruments.



D (R-PDS0-G14)

PLASTIC SMALL OUTLINE



NOTES:

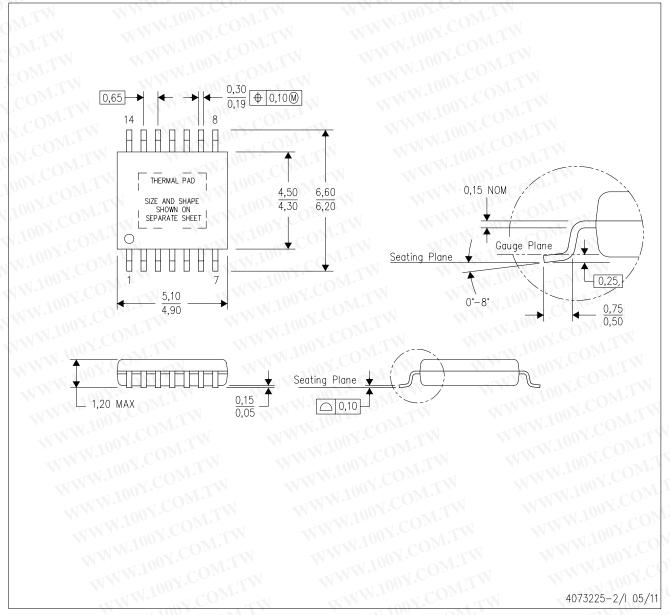
- All linear dimensions are in inches (millimeters).
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side. WWW.100Y.COM.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



WWW.100Y.C

PWP (R-PDSO-G14)

PowerPAD™ PLASTIC SMALL OUTLINE



NOTES:

- All linear dimensions are in millimeters.
- This drawing is subject to change without notice.
- Body dimensions do not include mold flash or protrusions. Mold flash and protrusion shall not exceed 0.15 per side.
- This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com http://www.ti.com.
- WWW.100Y.COM See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- Falls within JEDEC MO-153

PowerPAD is a trademark of Texas Instruments.



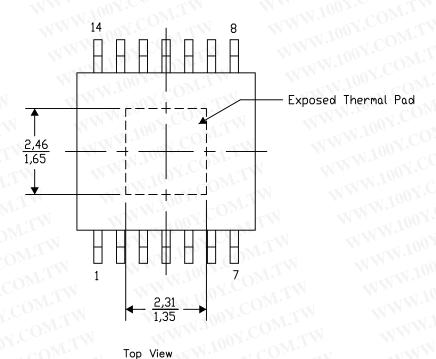
PWP (R-PDSO-G14) PowerPAD MSMALL PLASTIC OUTLINE

THERMAL INFORMATION

This PowerPADTM package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Exposed Thermal Pad Dimensions

4206332-2/AD 01/13

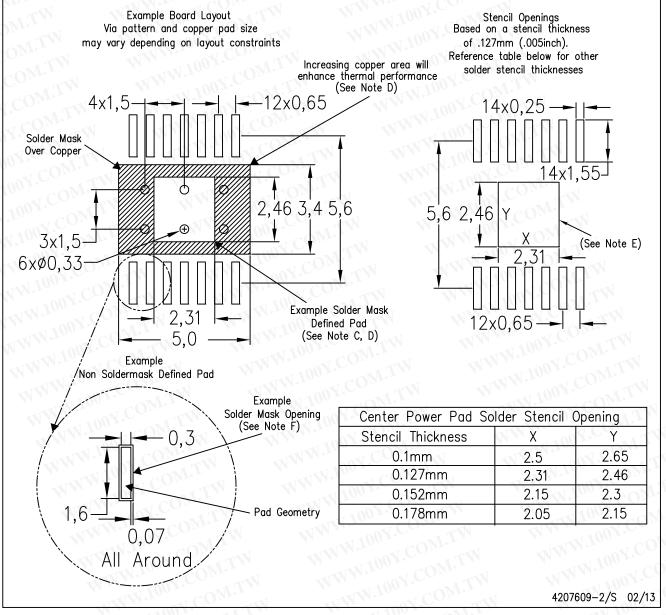
NOTE: A. All linear dimensions are in millimeters

PowerPAD is a trademark of Texas Instruments



PWP (R-PDSO-G14)

PowerPAD™ PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC—7525 for other stencil recommendations.
- F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PWP (R-PDSO-G14)

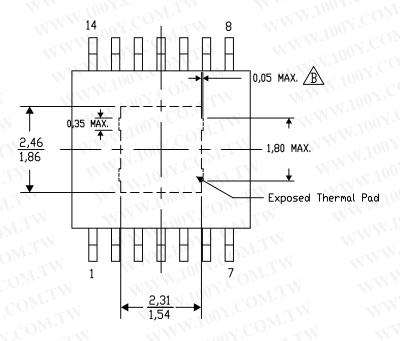
PowerPAD M SMALL PLASTIC OUTLINE

THERMAL INFORMATION

This PowerPADTM package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Top View

Exposed Thermal Pad Dimensions

4206332-44/AD 01/13

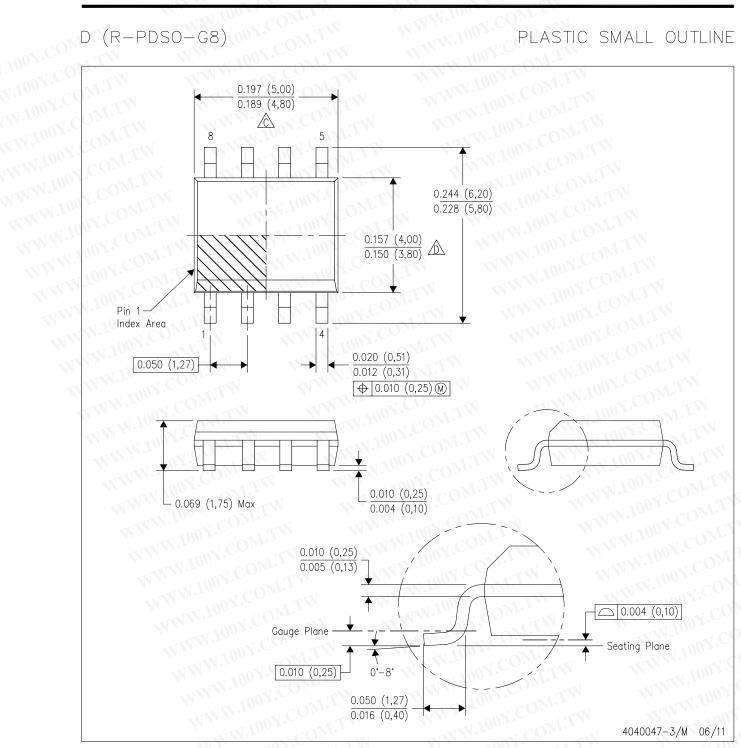
NOTE: A. All linear dimensions are in millimeters

🔼 Exposed tie strap features may not be present.

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PLASTIC SMALL OUTLINE



NOTES:

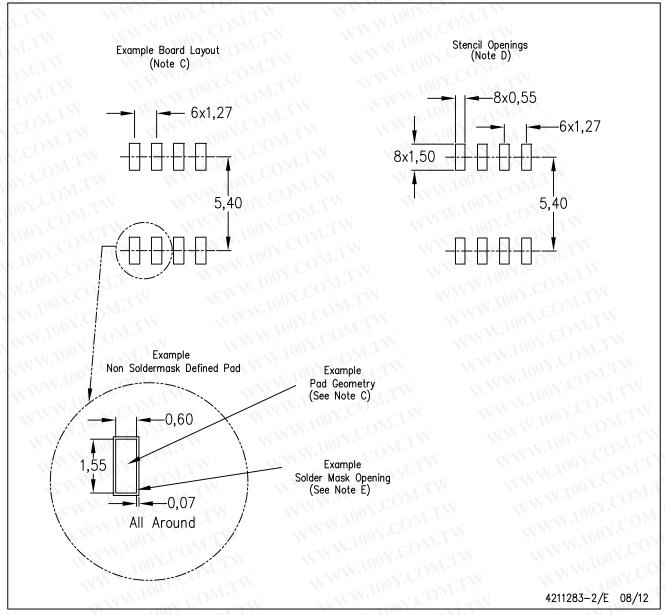
- All linear dimensions are in inches (millimeters).
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side. WWW.100Y.COM.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



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D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

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